

■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs.
- Low power loss and soft switching.
- High performance and high reliability IGBT with overheating protection.
- Both P-side and N-side alarm output available.
- Higher reliability because of a big decrease in number of parts in built-in control circuit.

■ Maximum ratings and characteristics

- Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item		Symbol	Rating		Unit	
			Min.	Max.		
Bus voltage	DC	V _{DC}	0	900	V	
	Surge	V _{DC(surge)}	0	1000	V	
	Short operating	V _{SC}	200	800	V	
Collector-Emitter voltage *1		V _{CES}	0	1200	V	
Inverter	Collector current	DC	I _C	-	75	A
		1ms	I _{CP}	-	150	A
		Duty=76.1% *2	-I _C	-	75	A
Collector power dissipation		One transistor *3	P _C	-	500	W
Brake	Collector current	DC	I _C	-	25	A
		1ms	I _{CP}	-	50	A
	Forward Current of Diode		I _F	-	25	A
	Collector power dissipation		One transistor *3	P _C	-	198
Supply voltage of Pre-Driver *4		V _{CC}	-0.5	20	V	
Input signal voltage *5		V _{in}	-0.5	V _{CC} +0.5	V	
Input signal current		I _{in}	-	3	mA	
Alarm signal voltage *6		V _{ALM}	-0.5	V _{CC}	V	
Alarm signal current *7		I _{ALM}	-	20	mA	
Junction temperature		T _j	-	150	°C	
Operating case temperature		T _{opr}	-20	100	°C	
Storage temperature		T _{stg}	-40	125	°C	
Isolating voltage (Terminal to base, 50/60Hz sine wave 1min.)		V _{iso}	-	AC2500	V	
Screw torque	Terminal (M5)		-	3.5	N·m	
	Mounting (M5)		-	3.5	N·m	

Note

*1 : V_{CES} shall be applied to the input voltage between terminal P and U or V or W or DB, N and U or V or W or DB.

*2 : $125^{\circ}\text{C}/\text{FRD } R_{\text{th(j-c)}}/(I_{\text{c}} \times V_{\text{F Max.}}) = 125/0.73(75 \times 3.0) \times 100 = 76.1\%$

*3 : P_C=125°C/IGBT R_{th(j-c)}=125/0.25=500W [Inverter]

P_C=125°C/IGBT R_{th(j-c)}=125/0.63=198W [Inverter]

*4 : V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13

*5 : V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 15,16,17,18 and 13.

*6 : V_{ALM} shall be applied to the voltage between terminal No.2 and 1, No6 and 5, No10 and 9, No.19 and 13.

*7 : I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

Electrical characteristics (at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$ unless otherwise specified.)

● Main circuit

Item		Symbol	Condition	Min.	Typ.	Max.	Unit	
Inverter	Collector current at off signal input	ICES	$V_{CE}=1200\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=75\text{A}$	Terminal	-	-	2.6	V
				Chip	-	-	-	
	Forward voltage of FWD	V_F	$-I_c=75\text{A}$	Terminal	-	-	3.0	V
Chip				-	-	-		
Brake	Collector current at off signal input	ICES	$V_{CE}=1200\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=25\text{A}$ Terminal	-	-	2.6	V	
	Forward voltage of Diode	V_F	$-I_c=25\text{A}$ Terminal	-	-	3.3		
Turn-on time		t_{on}	$V_{DC}=600\text{V}$, $T_j=125^\circ\text{C}$	1.2	-	-	μs	
Turn-off time		t_{off}	$I_c=75\text{A}$ Fig.1, Fig.6	-	-	3.6		
Reverse recovery time		t_{rr}	$V_{DC}=600\text{V}$, $I_F=75\text{A}$ Fig.1, Fig.6	-	-	0.3		

● Control circuit

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	I_{ccp}	Switching Frequency : 0 to 15kHz	-	-	18	mA
Supply current of N-line side pre-driver	I_{ccn}	$T_c=-20$ to 125°C Fig.7	-	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_Z	$R_{in}=20\text{k}\Omega$	-	8.0	-	V
Alarm signal hold time	t_{ALM}	$T_c=-20^\circ\text{C}$ Fig.2	1.1	-	-	ms
		$T_c=25^\circ\text{C}$ Fig.2	-	2.0	-	ms
		$T_c=125^\circ\text{C}$ Fig.2	-	-	4.0	ms
Limiting Resistor for Alarm	R_{ALM}		1425	1500	1575	Ω

● Protection Section ($V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	I_{oc}	$T_j=125^\circ\text{C}$	113	-	-	A
Over Current Protection Level of Brake circuit	I_{oc}	$T_j=125^\circ\text{C}$	38	-	-	A
Over Current Protection Delay time	t_{doc}	$T_j=125^\circ\text{C}$	-	10	-	μs
SC Protection Delay time	t_{sc}	$T_j=125^\circ\text{C}$ Fig.4	-	-	12	μs
IGBT Chip Over Heating Protection Temperature Level	T_{jOH}	Surface of IGBT chips	150	-	-	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{jH}		-	20	-	$^\circ\text{C}$
Over Heating Protection Protection Temperature Level	T_{cOH}	$V_{dc}=0\text{V}$, $I_c=0\text{A}$ Case Temperature	110	-	125	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{cH}		-	20	-	$^\circ\text{C}$
Under Voltage Protection Level	V_{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V_H		0.2	0.5	-	V

● Thermal characteristics($T_c=25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Unit
Junction to Case thermal resistance *8	Inverter	IGBT	$R_{th(j-c)}$	-	-	0.25	$^\circ\text{C/W}$
		FWD	$R_{th(j-c)}$	-	-	0.73	$^\circ\text{C/W}$
	Brake	IGBT	$R_{th(j-c)}$	-	-	0.63	$^\circ\text{C/W}$
Case to fin thermal resistance with compound			$R_{th(c-f)}$	-	0.05	-	

*8 : (For 1 device, Case is under the device)

● Noise Immunity ($V_{DC}=300\text{V}$, $V_{cc}=15\text{V}$, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width $1\mu\text{s}$, polarity \pm , 10minuets Judge : no over-current, no miss operating	± 2.0	-	-	kV
Common mode lightning surge	Rise time $1.2\mu\text{s}$, Fall time $50\mu\text{s}$ Interval 20s, 10 times Judge : no over-current, no miss operating	± 5.0	-	-	kV

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	V_{DC}	-	-	800	V
Operating Supply Voltage of Pre-Driver	V_{cc}	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

● Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	W_t	-	450	-	g

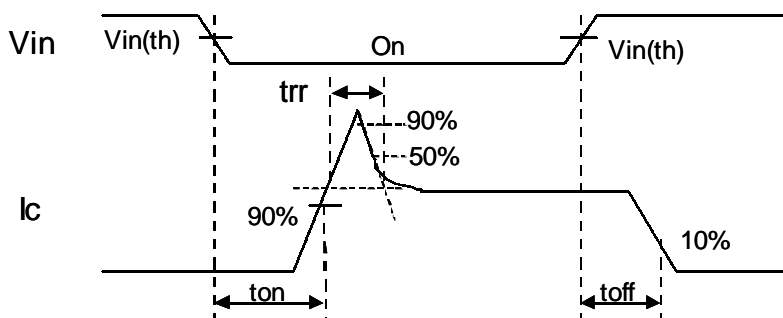
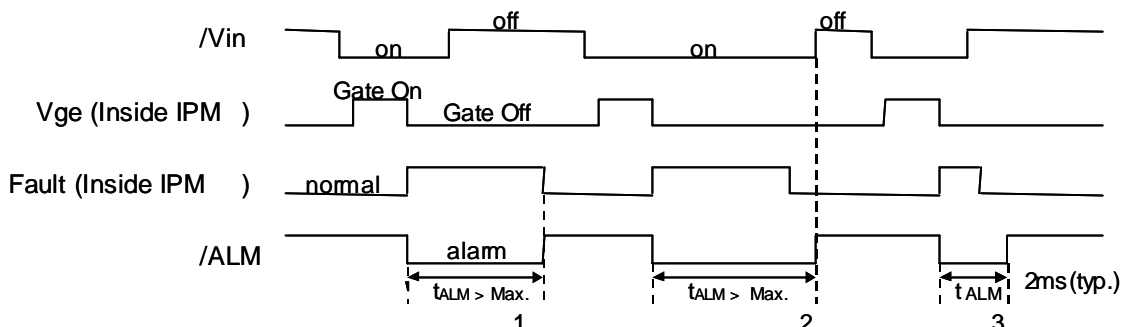


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input/Output Timing Diagram

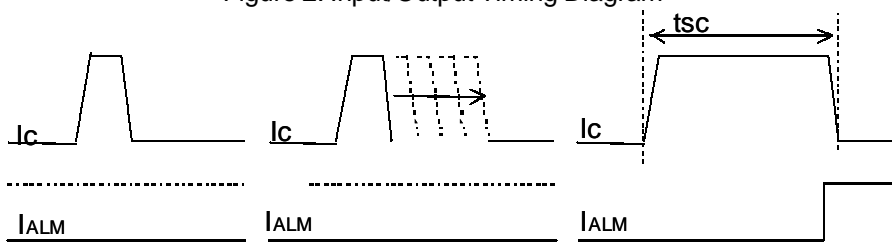


Figure.4 Definition of tsc

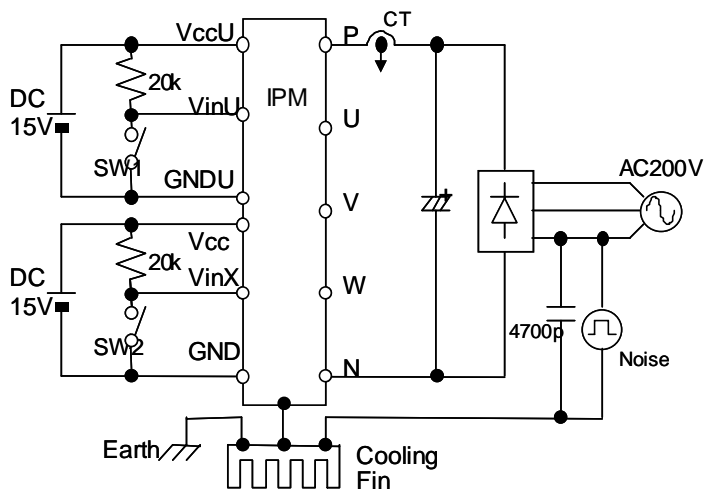


Figure 5. Noise Test Circuit

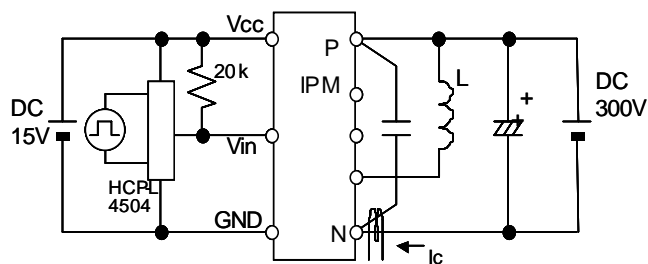


Figure 6. Switching Characteristics Test Circuit

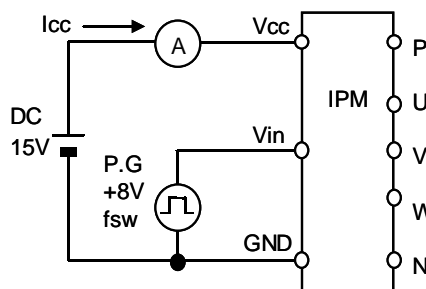
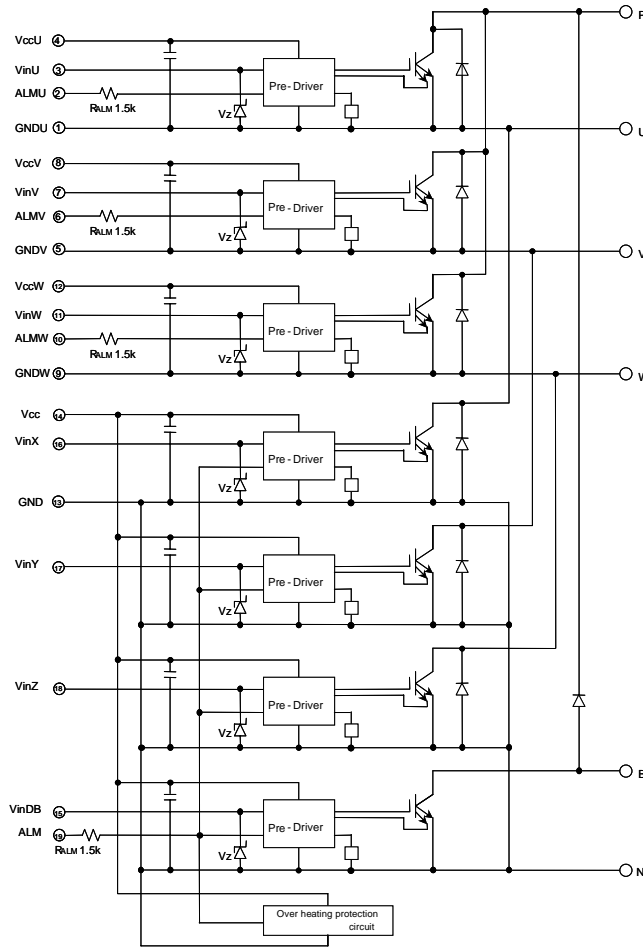


Figure 7. Icc Test Circuit

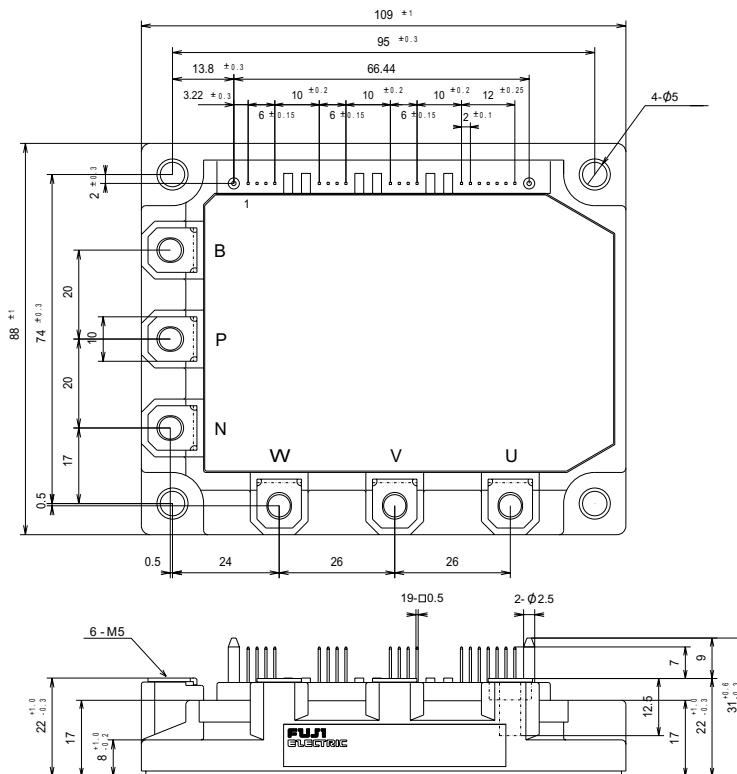
Block diagram



Pre-drivers include following functions

1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

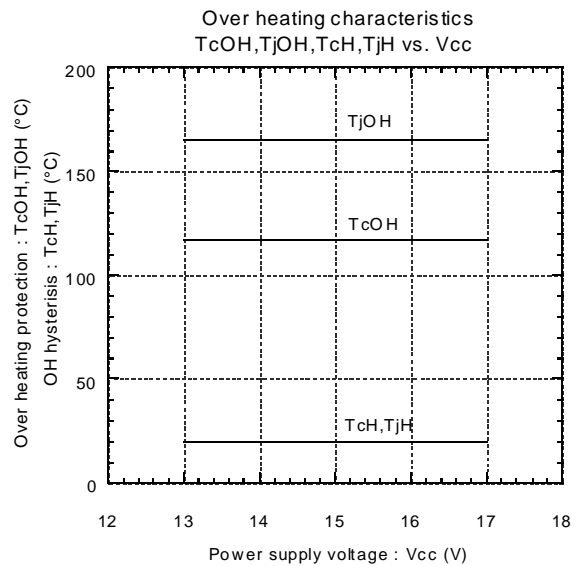
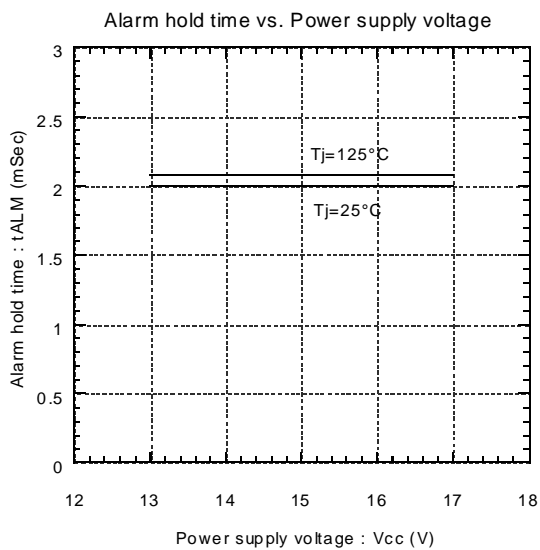
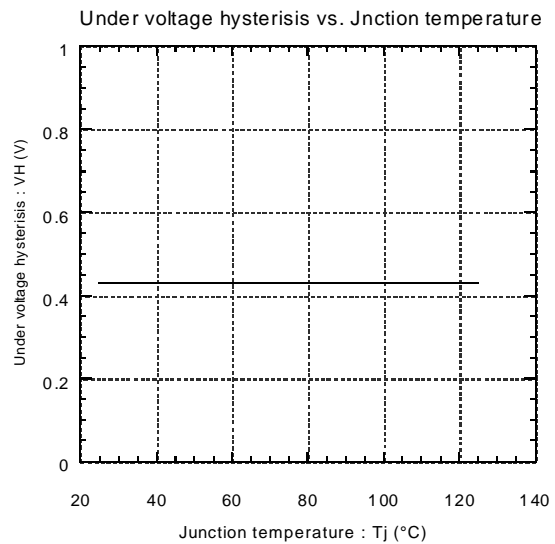
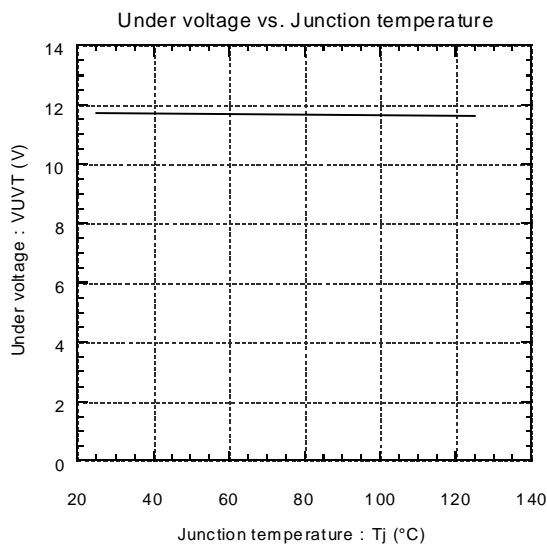
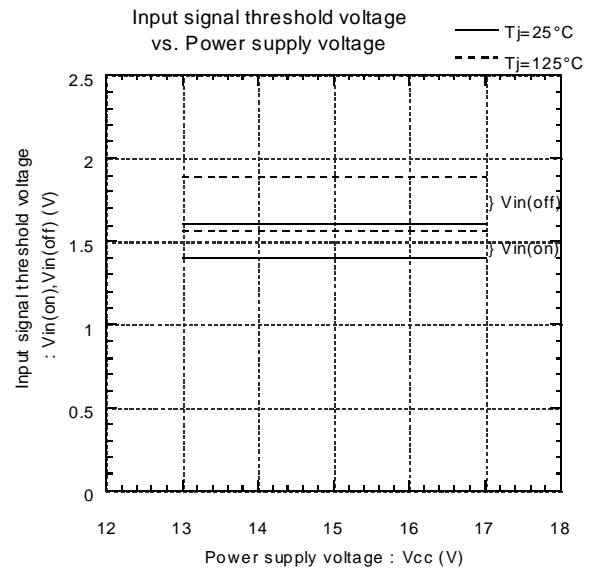
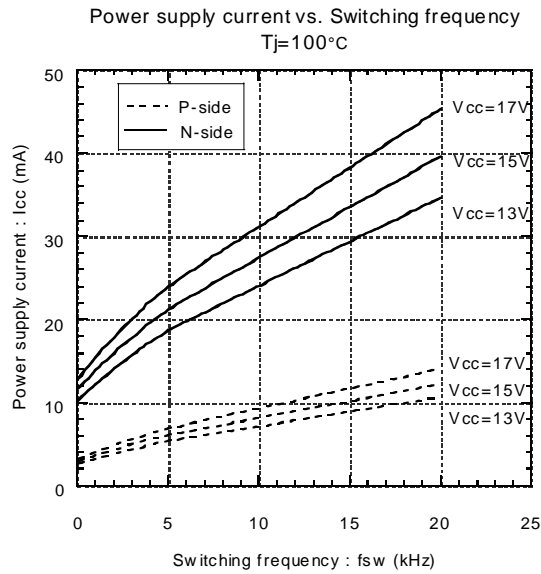
Outline drawings, mm



Mass : 450g

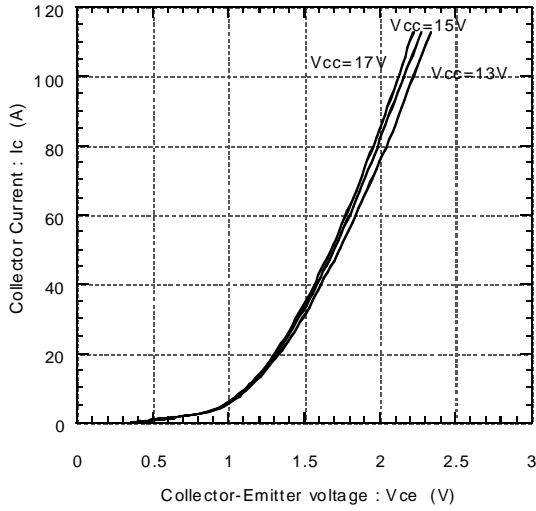
Characteristics

Control circuit characteristics (Representative)

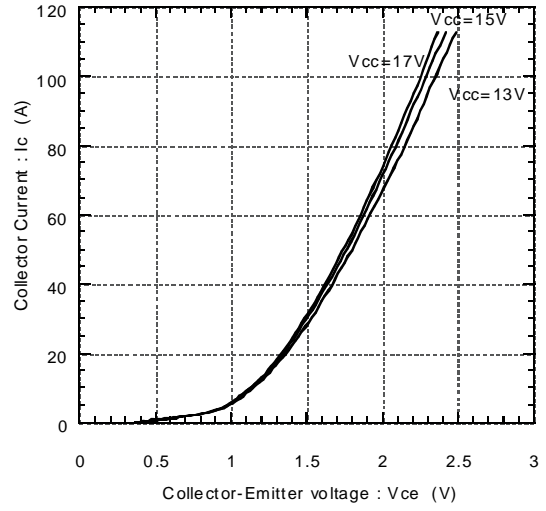


● Main circuit characteristics (Representative)

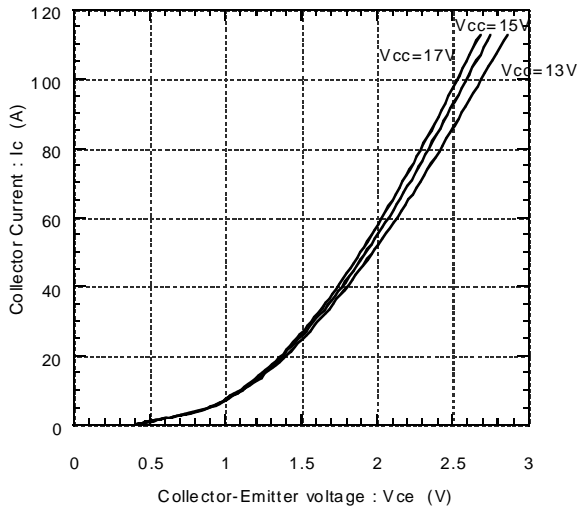
Collector current vs. Collector-Emitter voltage
Tj=25°C(Chip)



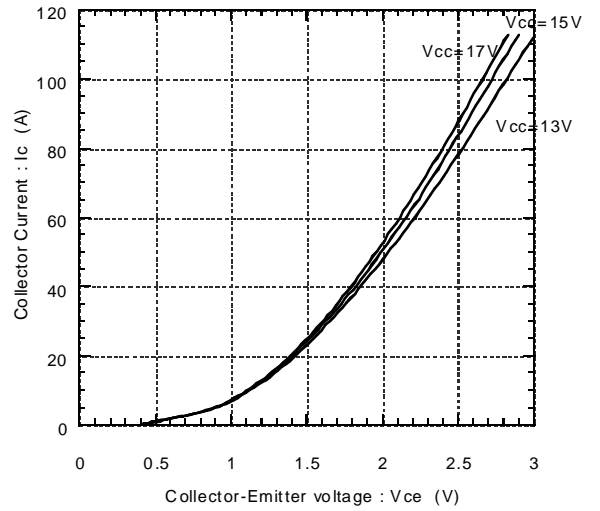
Collector current vs. Collector-Emitter voltage
Tj=25°C(Terminal)



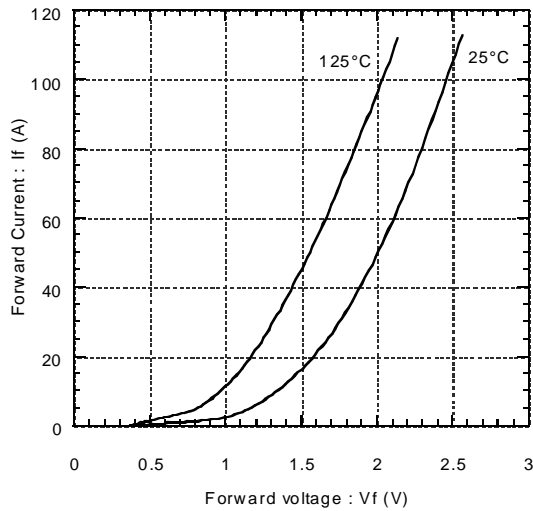
Collector current vs. Collector-Emitter voltage
Tj=125°C(Chip)



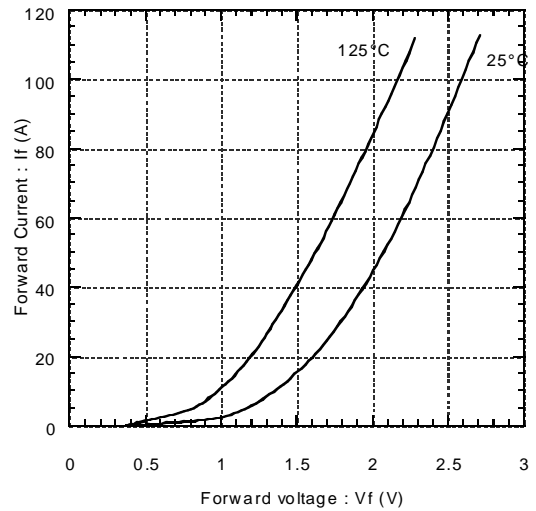
Collector current vs. Collector-Emitter voltage
Tj=125°C(Terminal)



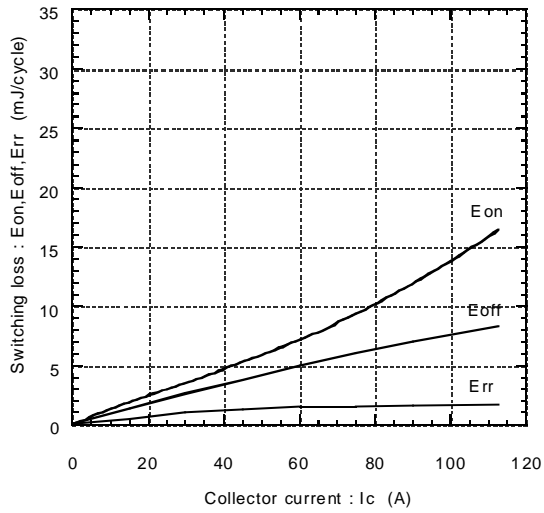
Forward current vs. Forward voltage
(Chip)



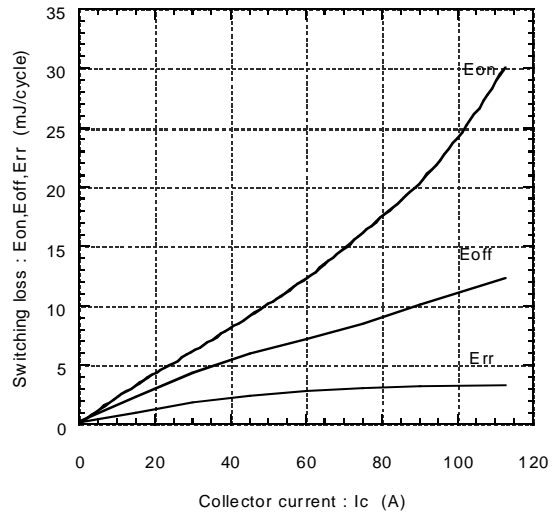
Forward current vs. Forward voltage
(Terminal)



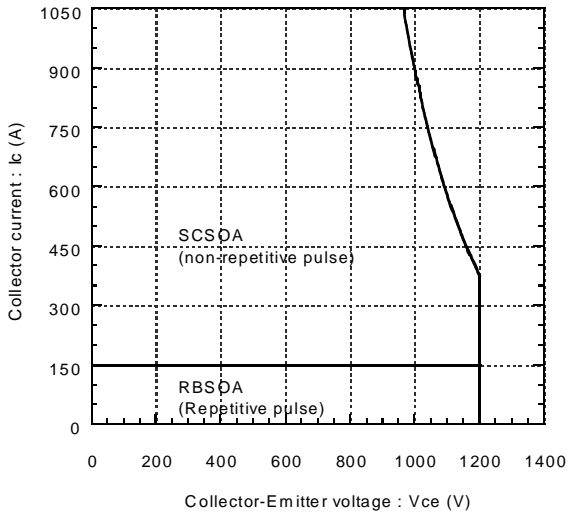
Switching Loss vs. Collector Current
 $E_{dc}=600V, V_{cc}=15V, T_j=25^\circ C$



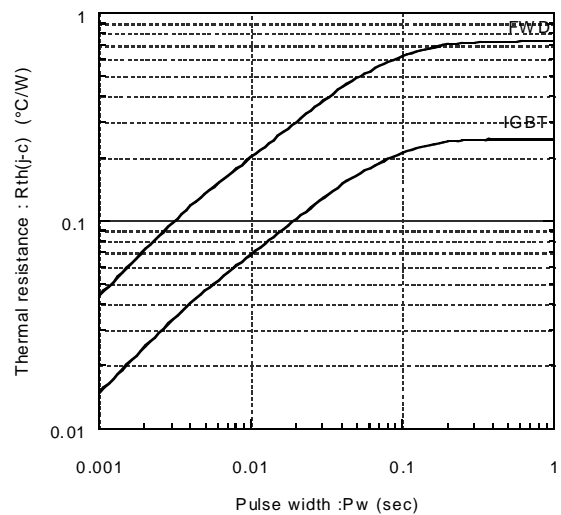
Switching Loss vs. Collector Current
 $E_{dc}=600V, V_{cc}=15V, T_j=125^\circ C$



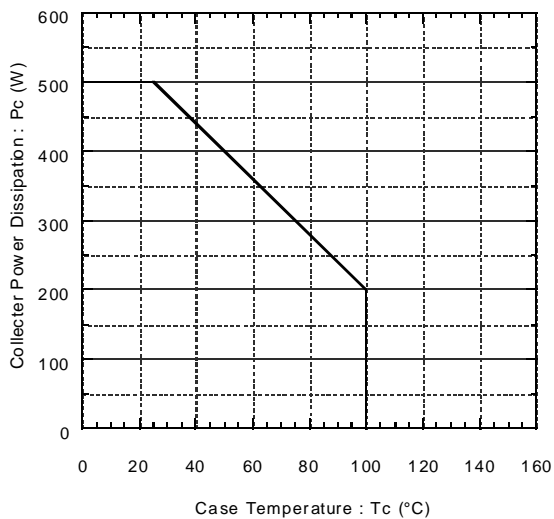
Reversed biased safe operating area
 $V_{cc}=15V, T_j \le 125^\circ C$



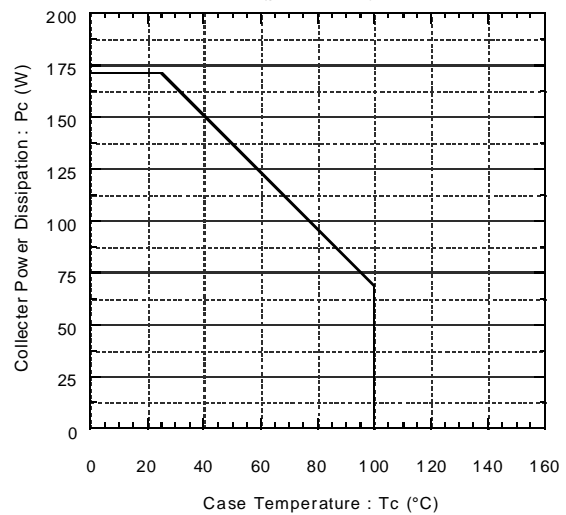
Transient thermal resistance

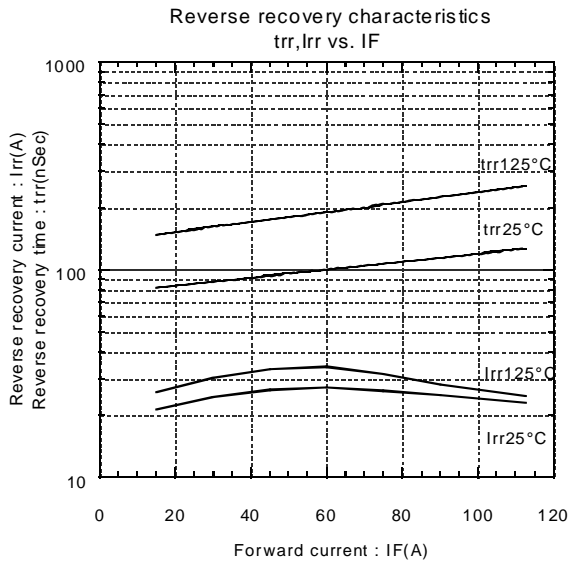
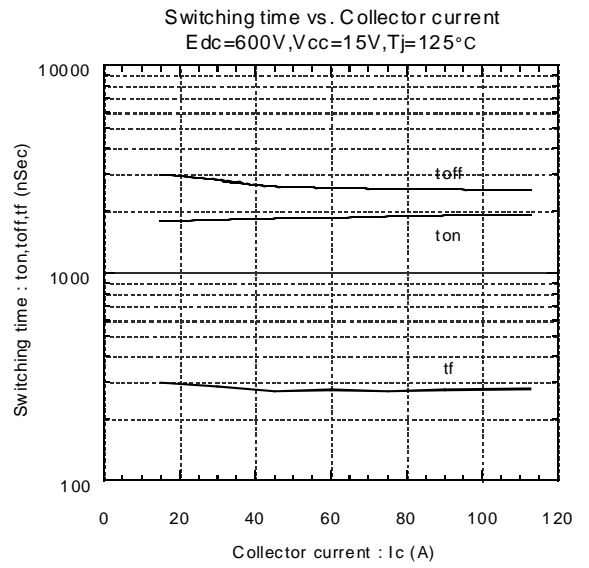
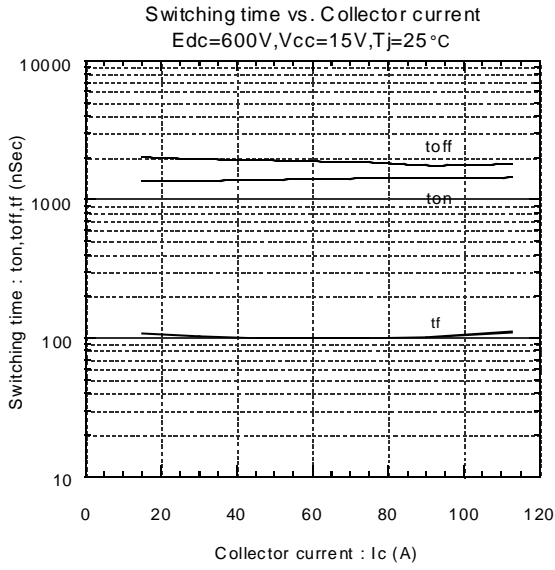


Power derating for IGBT
(per device)



Power derating for FWD
(per device)





● Dynamic Brake Characteristics (Representative)

